

CATHODE (-) END VIEW



SIDE VIEW



ANODE (+) END VIEW



BOTTOM VIEW



Click [here](#) for the 3D model.

Dimensions

Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	1.9mm +/-0.1mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
E	3.5mm REF
G	3.5mm REF
X	0.05mm REF

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	1000

General Information

Series	T543 HRA
Dielectric	Polymer Tantalum
Style	SMD Chip
Description	SMD, Polymer, Molded, Up Screening
Features	Non-Combustible, Low Profile, Low ESR, High Reliability
RoHS	Yes
Termination	Tin
AEC-Q200	No
Component Weight	262.9 mg
Shelf Life	52 Weeks
MSL	3

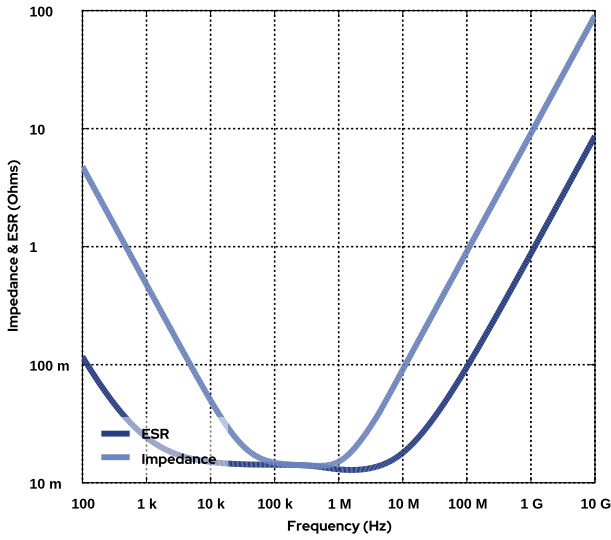
Specifications

Capacitance	330 uF
Capacitance Tolerance	20%
Voltage DC	2.5 VDC (105C)
Temperature Range	-55/+105°C
Rated Temperature	105°C
Humidity	60C, 90% RH, 500 Hours
Dissipation Factor	10% 120Hz 25C
Failure Rate	N/A
Resistance	25 mOhms (100kHz)
Ripple Current	2735 mA (rms, 100kHz 45C)
Leakage Current	82.5 uA (5min 25°C)
Testing and Reliability	Standard Testing Only

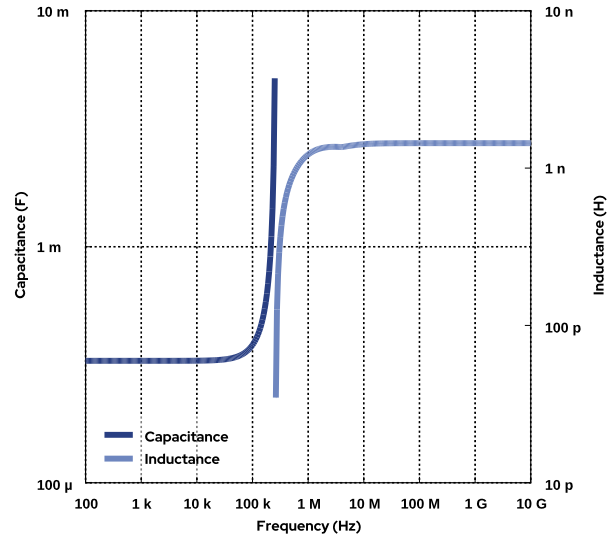
Simulations

For the complete simulation environment please visit [K-SIM](#).

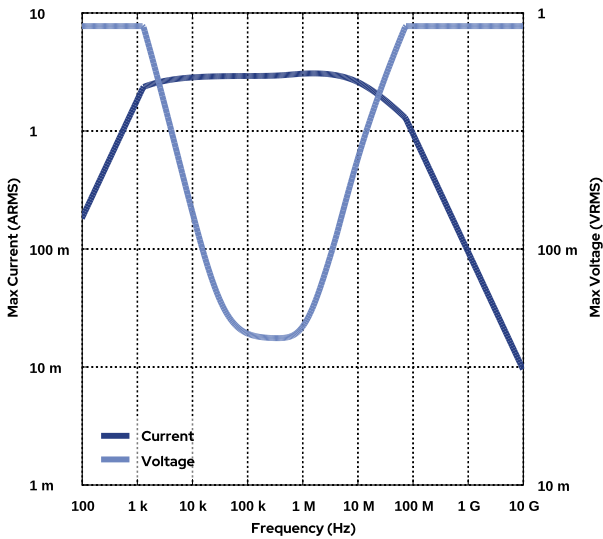
Impedance and ESR



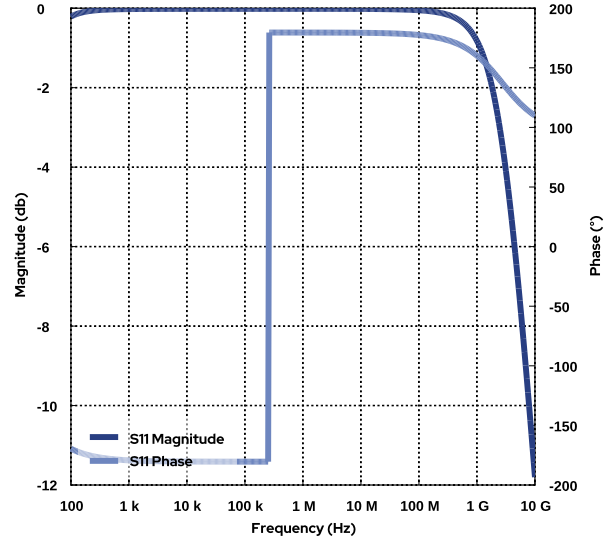
Capacitance and Inductance

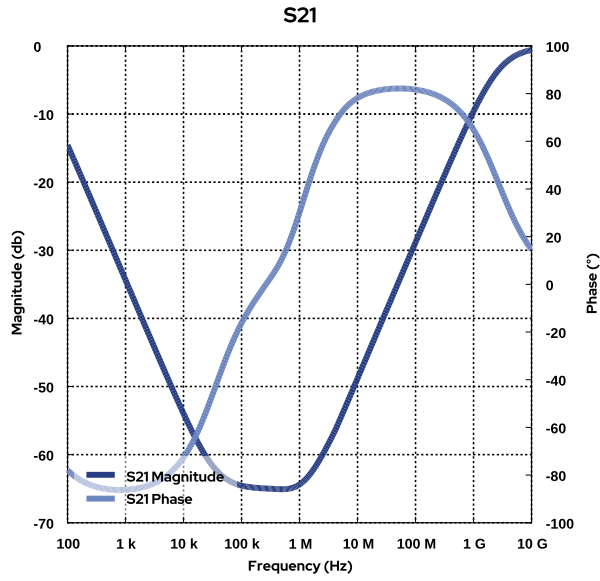


Current and Voltage



S11





These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.
- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
- The effects shown herein are based on measured data from a multiple part sample of the parts in question.
- Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
- The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages generated at any other harmonics.
- Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.